



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Toshiya UEMURA, et al.

Serial No.: 09/819,952

Group Art Unit: 2815

Filed: March 29, 2001

Examiner: Bradley W. Baumeister

For: LIGHT-EMITTING DEVICE USING GROUP III NITRIDE GROUP COMPOUND  
SEMICONDUCTOR AND METHOD FOR MANUFACTURING IT

Honorable Commissioner of Patents  
Washington, D.C. 20231

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**RESUBMISSION OF AMENDMENT UNDER 37 C.F.R. § 1.111**

Sir:

Applicant hereby resubmits the Amendment originally filed herein on January 30, 2003. The Amendment is being resubmitted solely for the purpose of correcting the Version with Markings to Show Changes Made which was incorrect in the Amendment as originally filed.

In response to the Office Action dated September 5, 2002, please amend the above-identified application as follows:

**IN THE CLAIMS:**

**Please amend the claims to read as follows:**

1. (Amended) A light-emitting semiconductor device comprising:  
a substrate;  
a plurality of semiconductor layers which comprise group III nitride group compound semiconductors and are laminated on said substrate by crystal growth;  
an emission layer formed on a first side of the substrate; and  
a mirror surface formed on a second side of the substrate opposite the first side, said mirror surface comprising:  
a light transmission layer which directly contacts said substrate, has luminous transparency, and comprises at least one material selected from a group consisting of metal oxides and ceramics; and